# LET THERE BE MORELIGHT

CYGNO Collaboration

#### New test at LNF

- In LEMON we are trying to study in more details luminescence phenomena induced by electrons below the last GEM as a part of more general studies about gain saturation and possible solutions;

- A conductive (7 $\Omega$ / $\Box$ ) glass ITO-coated is used to accelerate them;



- Thickness 0.7 mm;
- Transmittance at 550 nm: 89%;
- Reflection less than 4%;

#### New test at LNF



VGEM = 365 V No field below GEM#3

VGEM = 365 V 16.7 kV/cm field below GEM#3



We did the usual scan on Electric field below the GEM.

Results obtained are similar (within a 25%) with the ones obtained with the Mesh.









To check how the external electric field "influences" the field in the GEM, we applied a negative voltage to ITO. With a field of -15.8 kV/cm a decrease of 10% in light was observed (to be compared with an increase of about 7 for +15.8 kV/cm)



The exponential extrapolation to negative field data indicates a continuous increase up to about 8-10 kV/cm. Then another process arises;



Electric field in the holes GEM#3 can be evaluated as

Mesh

$$E_h = \frac{V_{GEM}}{50\mu m} + E_M$$

We studied the behavior of light and current as a function  $E_h$ ;



When increasing  $V_{GEM}$  light and current have the same behavior; Effect of the  $E_M$  seems completely different;





#### The light yield depends almost only on the sum of $V_{\text{GEM}}$

![](_page_9_Picture_0.jpeg)

![](_page_9_Figure_1.jpeg)

Same behavior for the current too: it depends almost only on the sum of  $V_{\text{GEM}}$ 

![](_page_10_Picture_0.jpeg)

![](_page_10_Figure_1.jpeg)

The light yield depends almost only on the sum of  $V_{\text{GEM}}$  and on the Field below the third GEM;

![](_page_11_Picture_0.jpeg)

![](_page_11_Figure_1.jpeg)

Same behavior for the current too: it depends almost only on the sum of  $V_{\rm GEM\,+}$  on the ITO voltage.

![](_page_12_Picture_0.jpeg)

![](_page_12_Figure_1.jpeg)

The ratio between light and charge seems to depend only on the ITO voltage

![](_page_13_Figure_1.jpeg)

![](_page_13_Figure_2.jpeg)

### Different behavior when changing $V_{\text{GEM}}$

Because of the saturation, we expect that increasing the voltage on GEM1 with GEM2/GEM3 at high voltages (460V) provides lower gain increases w.r.t. GEM2/GEM3 at lower voltages (410V)

![](_page_14_Figure_2.jpeg)

What happens if we turn On the ITO field in the configuration with low GEM2/GEM3 gain?

![](_page_15_Figure_2.jpeg)

Light yield can be completely recovered

But the curves are not "parallel"!

![](_page_16_Figure_2.jpeg)

Light yield can be completely recovered

What happens if we turn On the ITO field in the configuration with low GEM2/GEM3 gain?

![](_page_17_Figure_2.jpeg)

Light yield can be completely recovered

But the curves are "parallel"!

![](_page_18_Figure_2.jpeg)

![](_page_19_Figure_1.jpeg)

Gain increases with the same behavior if ITO is On, with low GEM voltage or ITO is OFF with high GEM voltage;

And the increase is lower w.r.t. the case of low GEM voltage and ITO Off.

Probably the ITO process have same saturation behavior.

![](_page_20_Figure_1.jpeg)

Slightly better behavior with even lower GEM voltage